## 제23회 한국반도체학술대회

2016년 2월 22일(월)-24일(수), 강원도 하이원리조트

## J. Nano-Science & Technology 분과

Room H 육백 I (6층)

2016년 2월 24일(수) 10:10-11:40

[WH2-J] Two-Dimensional Materials / Spintronics

좌장: 김근수(포항공과대학교)

WH2-J-1	10:10-10:40	[초청] Ionic Liquid Gated Field Effect Transistors based on Atomically Thin Transition Metal Dichalcogenides Crystals Sanghyun Jo, Davide Costanzo, Helmuth Berger, and Alberto F. Morpurgo Department of Quantum Matter Physics and Group of Applied Physics, University of Geneva, Switzerland
WH2-J-2	10:40-10:55	Method To Eliminate Gate and Drain Bias Stress in WSe <sub>2</sub> Field Effect Transistors with Single Channel Pulsed <i>I-V</i> Measurement Jun-Mo Park, In-Tak Cho, Won-Mook Kang, Byung-Gook Park, and Jong-Ho Lee Department of Electrical and Computer Engineering, Seoul National University
WH2-J-3	10:55-11:10	그래핀 RF 소자의 Drain-gate Coupling에 의한 다중 신호 공진 현상 이상경 <sup>1,2</sup> , 조천흠 <sup>1,3</sup> , 유태진 <sup>1,2</sup> , 이호인 <sup>1,2</sup> , A. N. R. Reza <sup>1,2</sup> , 이병훈 <sup>1,2,3</sup> <sup>1</sup> 미래전자소자 연구센터, <sup>2</sup> 광주과학기술원 신소재공학부, <sup>3</sup> 광주과학 기술원 나노바이오재료전자공학과
WH2-J-4	11:10-11:25	Low Current Switching Induced by Large Spin Orbit Torque of Tungsten Seung-heon Chris Baek <sup>1,2</sup> , Kyung-Woong Park <sup>1</sup> , and Byong-Guk Park <sup>1</sup> <sup>1</sup> Department of Materials Science and Engineering, KAIST, <sup>2</sup> Department of Electrical Engineering, KAIST
WH2-J-5	11:25-11:40	Electric Field Induced Magnetic Anisotorpy Control with Magnetic Tunnel Junction Structrues  Kyung-Woong Park <sup>1,2</sup> , Seung-Heon Chris Baek <sup>1</sup> , Dae-Hoon Kim <sup>1</sup> , Soo-Man Seo <sup>2</sup> , Sung-Woong Chung <sup>2</sup> , and Byong-Guk Park <sup>1</sup> <sup>1</sup> Department of Materials and Science and Engineering, KAIST,

<sup>2</sup>Research and Development Division, SK hynix Inc.